

Ferromagnetic Semiconductors

Ilmenite-Hematite solid solutions $(\text{FeTiO}_3)_{(1-x)} / (\text{Fe}_2\text{O}_3)_x$

D. Allen, L. Falco, P. Padmini, T. Klein,
R.K.Pandey, G. Mankey, W. Butler, R. Schad

NSF MRSEC

THE UNIVERSITY OF ALABAMA

Center For Materials For Information Technology
An NSF Materials Research Science and Engineering Center

Ferromagnetic Semiconductors

Mn in GaAs (Matsukura et al. 1977)

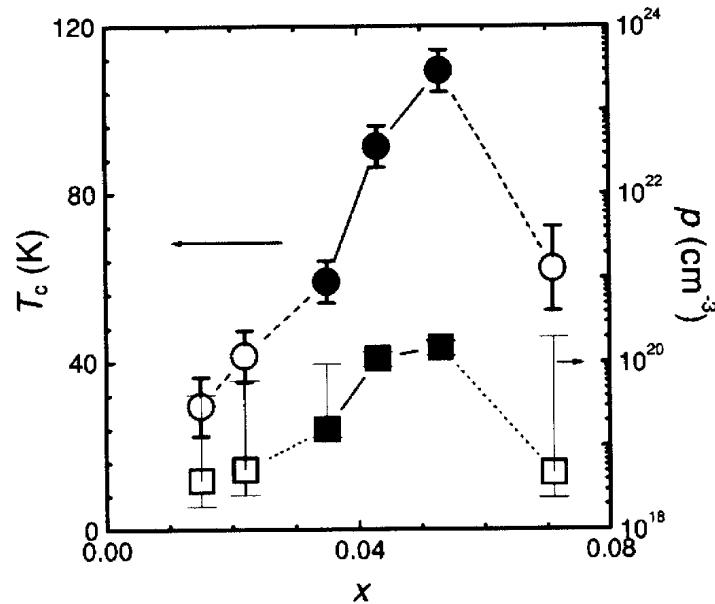


FIG. 2. Mn composition dependence of ferromagnetic transition temperature T_c and hole concentration p . Samples on the metal side of the metal insulator transition are shown by the closed symbols (see also Fig. 3).

Goal: Raise T_c

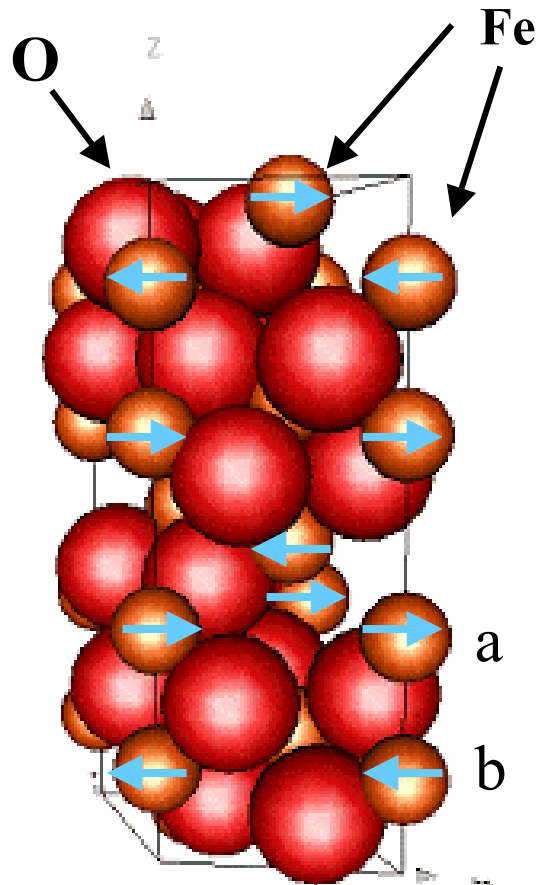
- More Magnetic Ions
- More Carriers
- High Fermi Energy DOS

Problems:

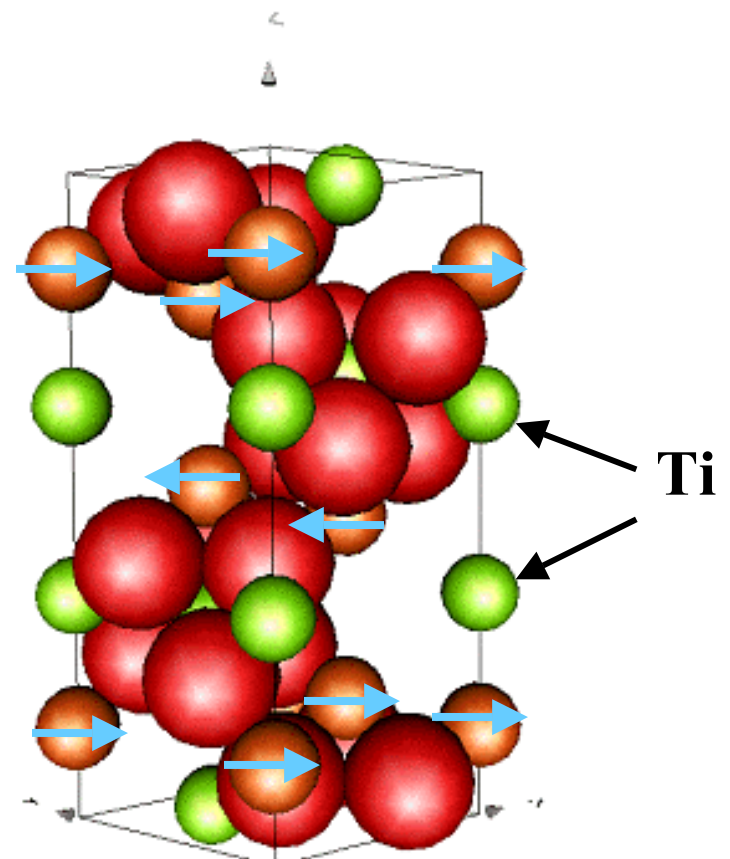
- More Disorder
- Self-compensation
- Only p-type conduction

Ferromagnetic Semiconductors

Hematite

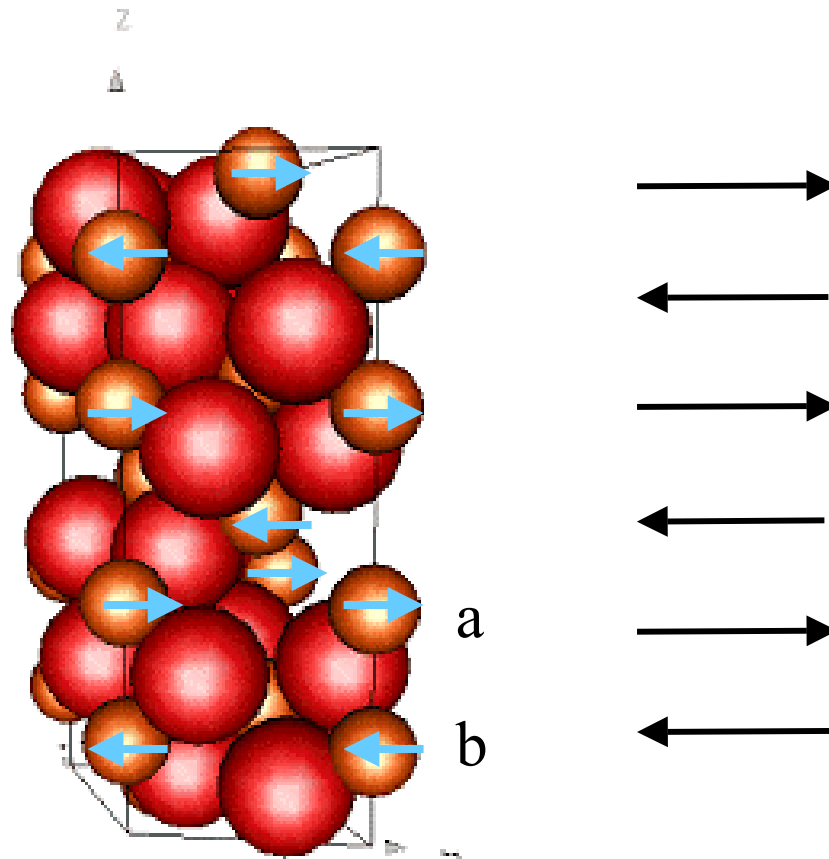


Ilmenite



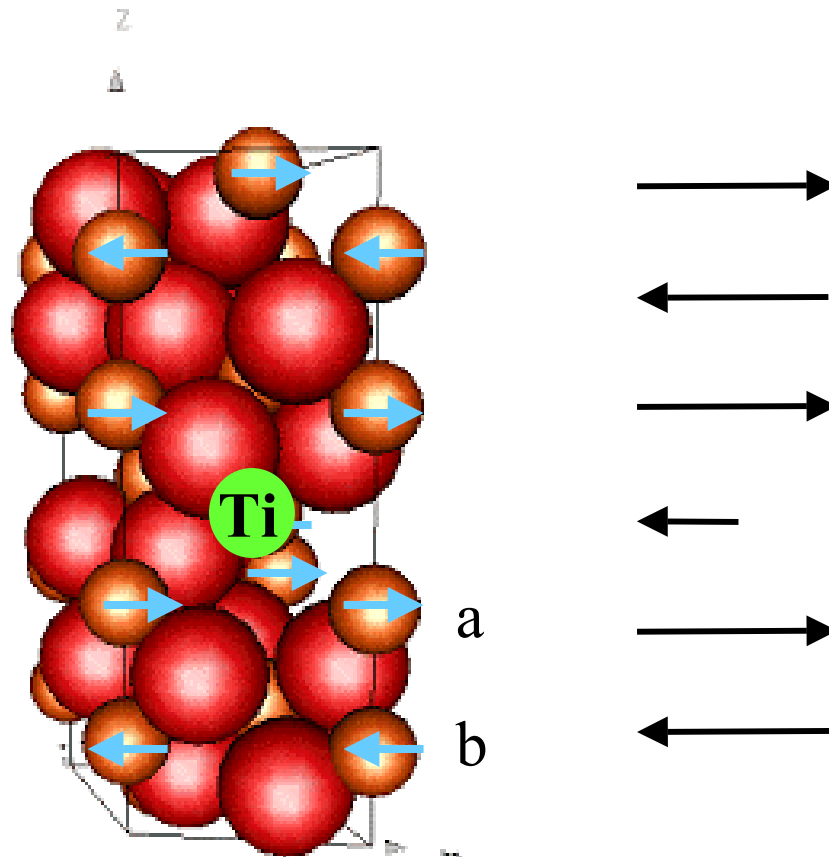
Ferromagnetic Semiconductors

Hematite / Ilmenite



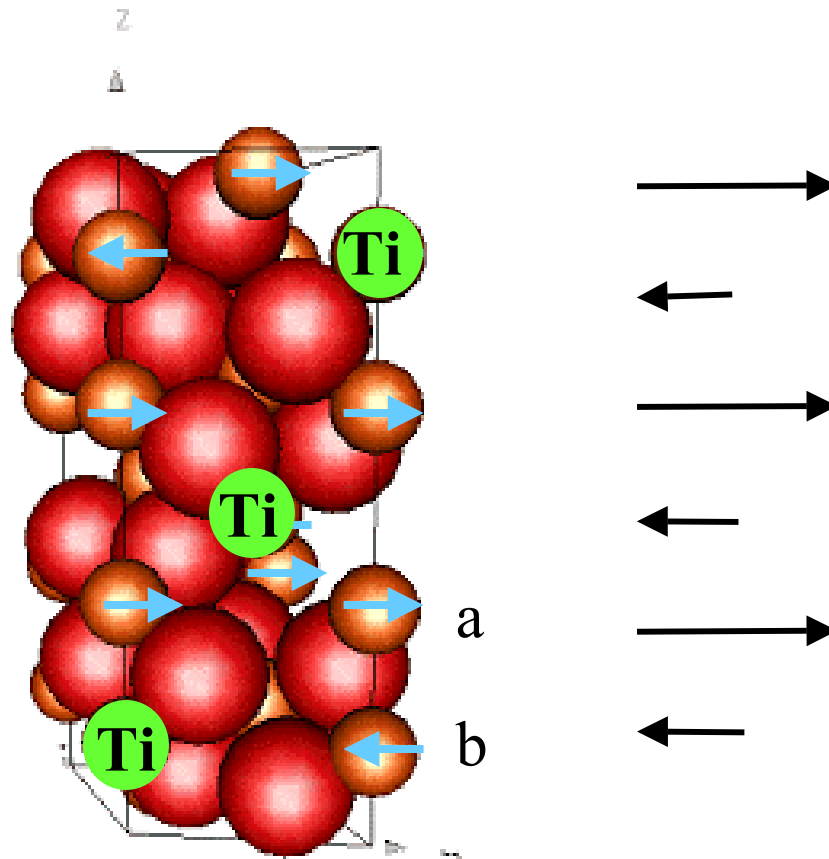
Ferromagnetic Semiconductors

Hematite / Ilmenite



Ferromagnetic Semiconductors

Hematite / Ilmenite



Ferromagnetic Semiconductors

Optical Properties: Ilmenite/hematite film on MgO

Transparent Ilmenite/hematite films on MgO
band gap!

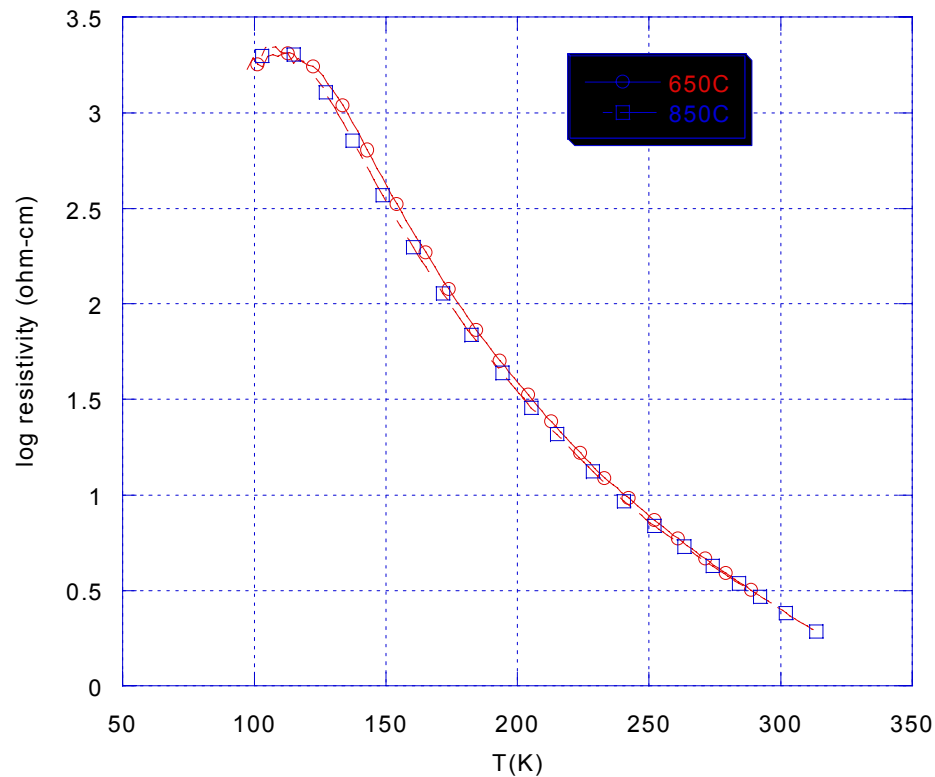
19nm $(\text{FeTiO}_3)_{0.67} (\text{Fe}_2\text{O}_3)_{0.33}$

33nm $(\text{FeTiO}_3)_{0.80} (\text{Fe}_2\text{O}_3)_{0.20}$



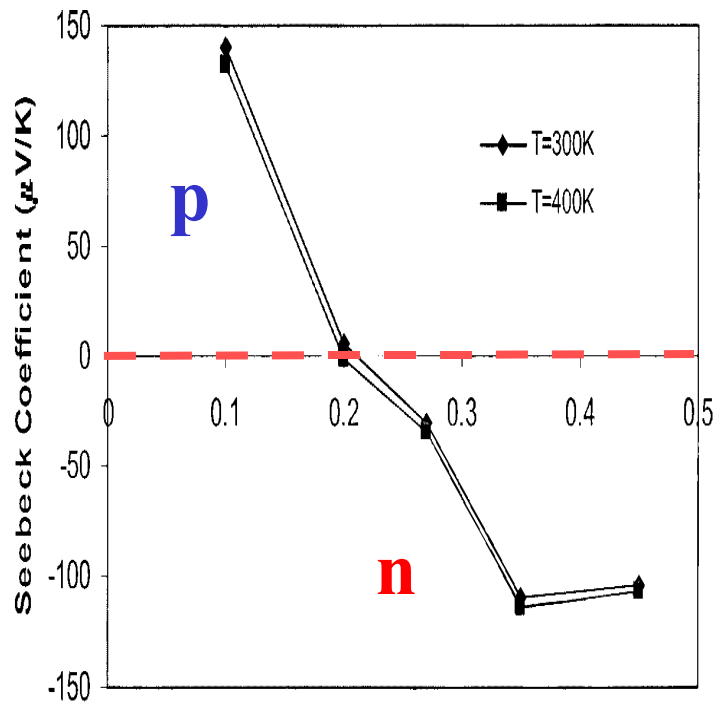
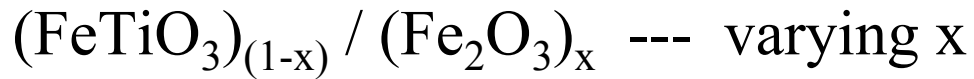
Ferromagnetic Semiconductors ilmenite-hematite // electrical properties

Resistivity plot for $x=0.45$ thin film
prepared at different temperatures



IH shows **semiconducting**
electrical properties

Ferromagnetic Semiconductors
ilmenite-hematite // doping

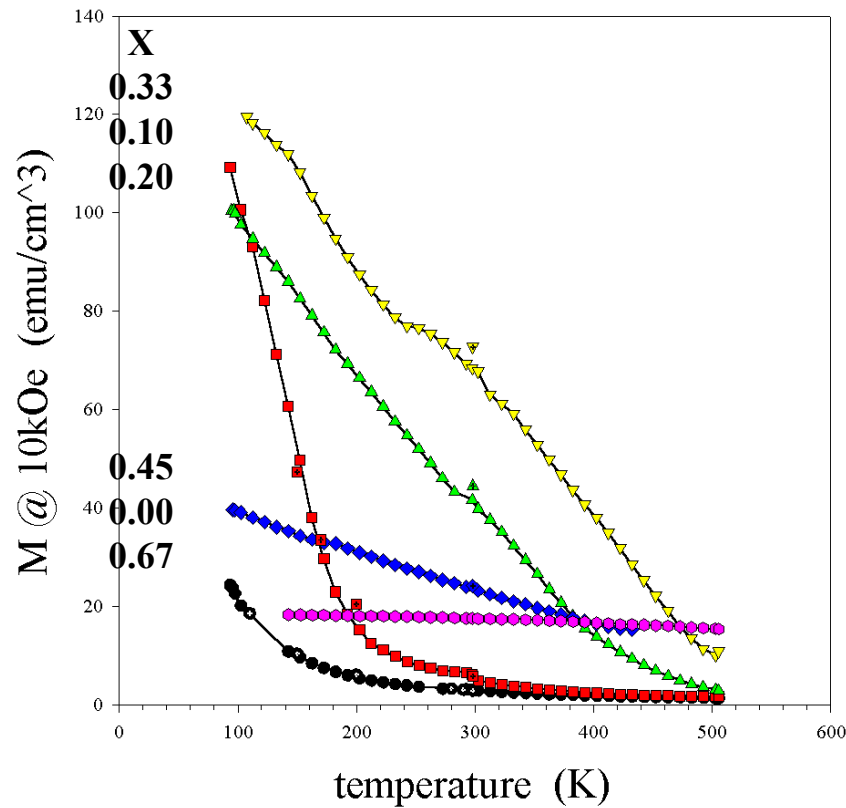


p- or n- semiconducting

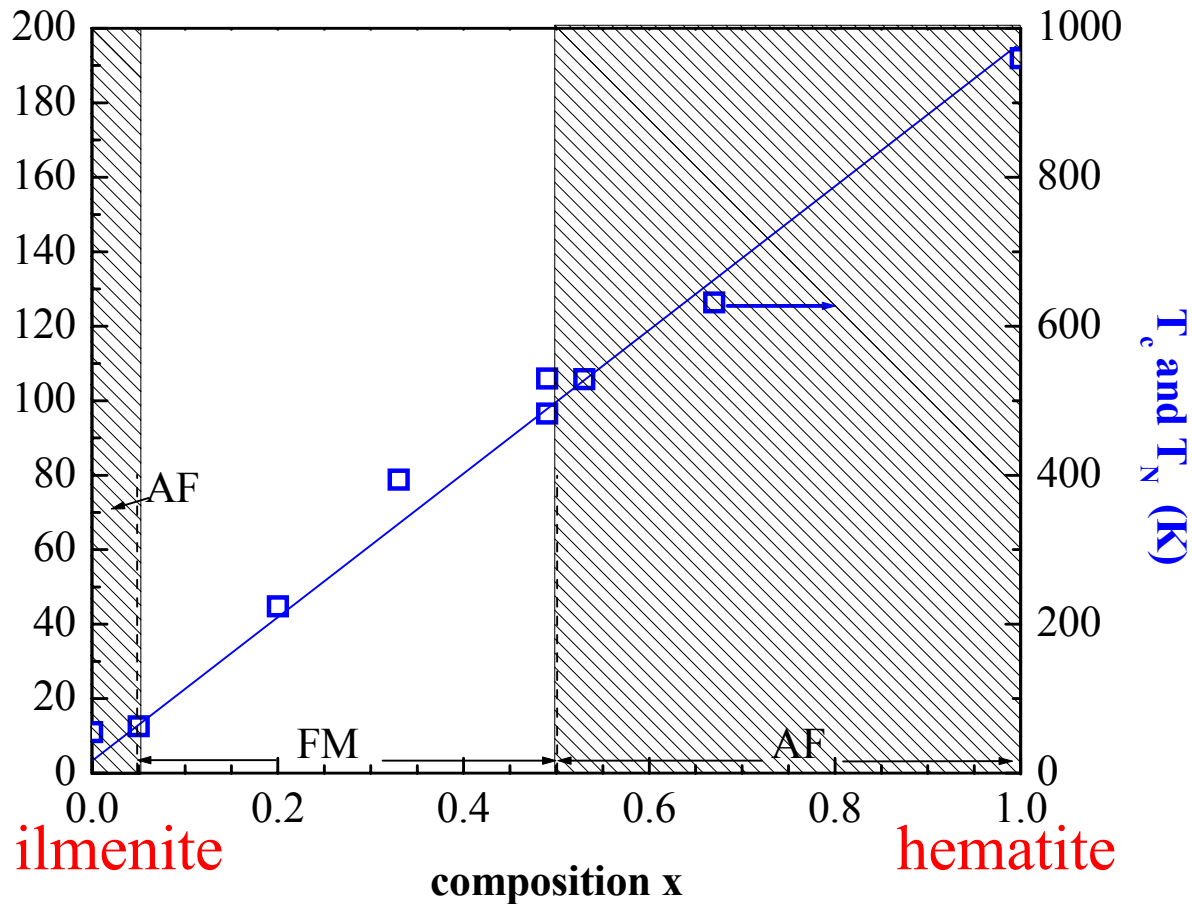
ilmenite Composition x => hematite

Ferromagnetic Semiconductors ilmenite-hematite // magnetic properties (bulk)

$(\text{FeTiO}_3)_{(1-x)} / (\text{Fe}_2\text{O}_3)_x$ --- varying x

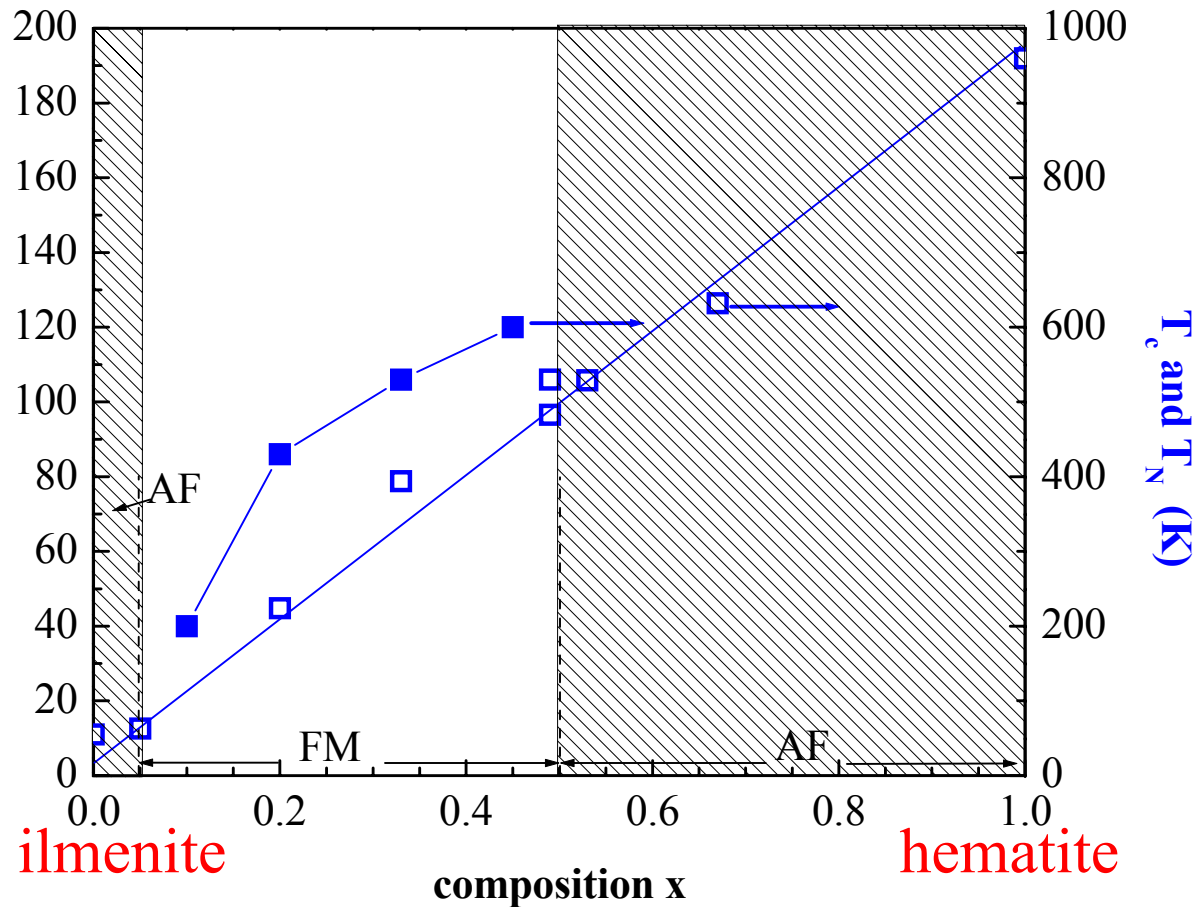


Ferromagnetic Semiconductors ilmenite-hematite // magnetic properties (bulk)



open symbols: Ishikawa, Akimoto J.Phys.Soc.Jap.12, 1083 (1957)

Ferromagnetic Semiconductors ilmenite-hematite // magnetic properties (bulk)

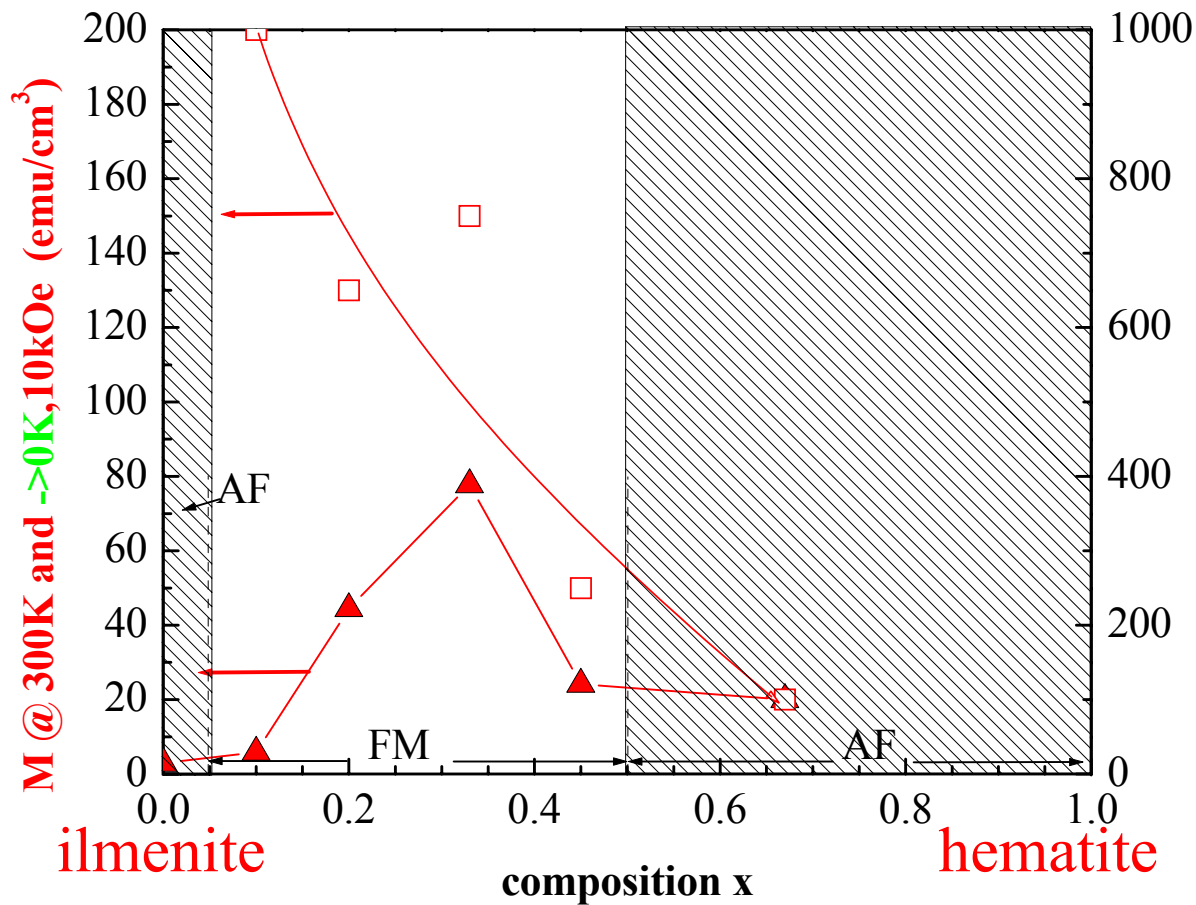


enhanced T_c

open symbols: Ishikawa, Akimoto J.Phys.Soc.Jap.12, 1083 (1957)

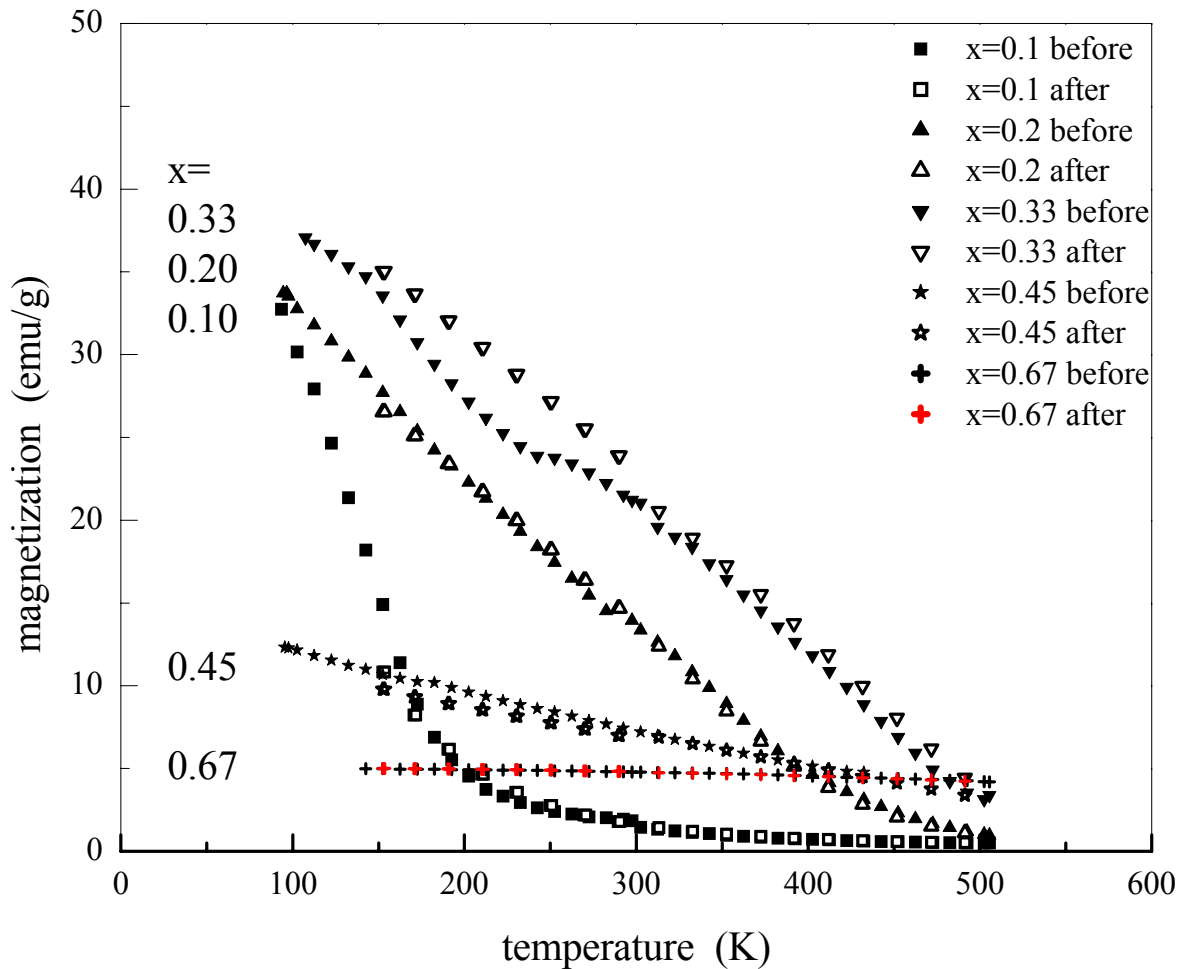
Ferromagnetic Semiconductors

ilmenite-hematite // magnetic properties (bulk)



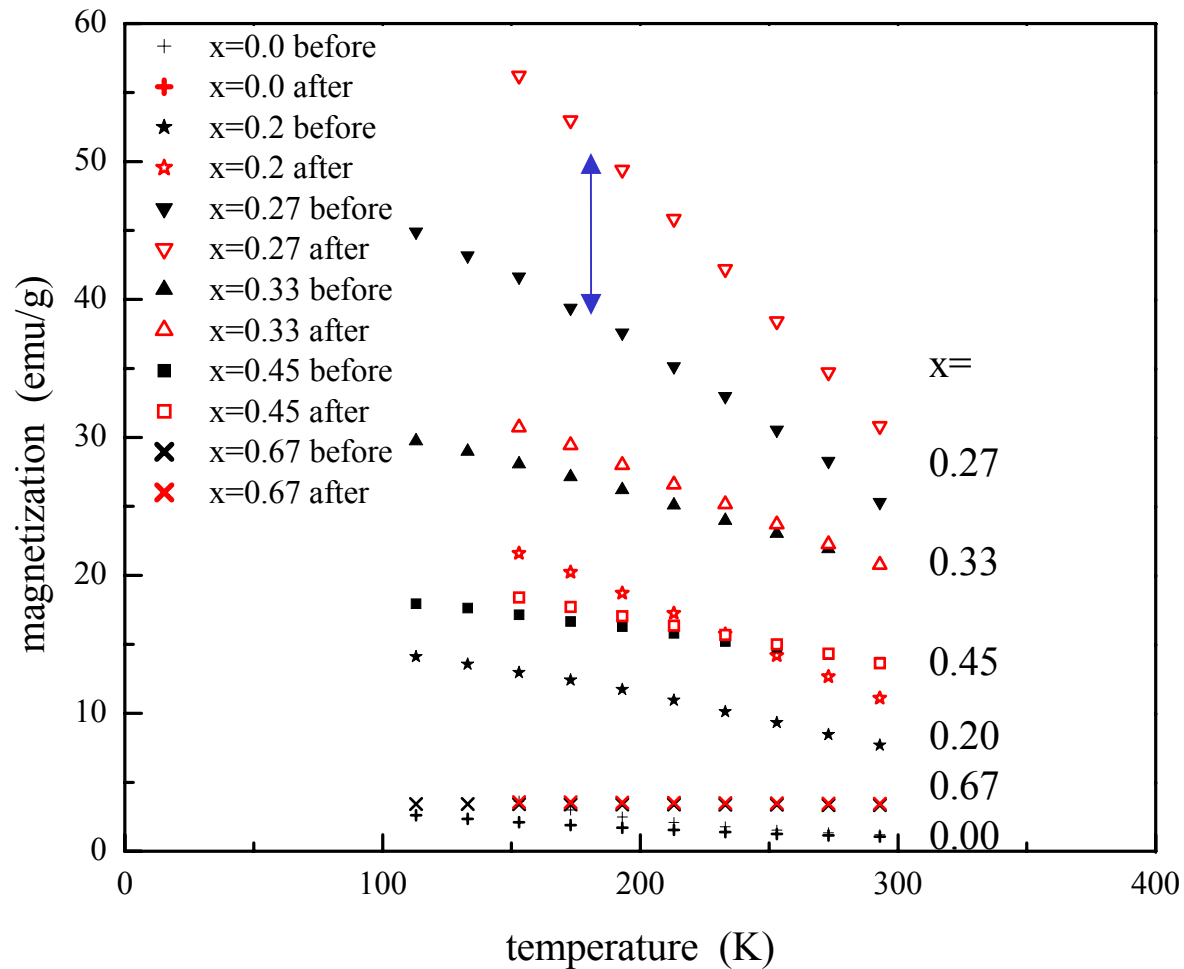
Ferromagnetic Semiconductors

Magnetic Moments are radiation hard against neutron irradiation



Ferromagnetic Semiconductors

Magnetic Moments are enhanced by proton irradiation



Ferromagnetic Semiconductors

Future Work

- epitaxial layers on various substrates using PLD and ALD
- enforced chemical ordering through combined $\text{TiO}_2/\text{Fe}_2\text{O}_3$ ALD
- understanding electric transport mechanism theory/experiment
- use of other dopants
- pn-junctions, bipolar spin transistor